



Features

- IEC 61000-4-2 (ESD): Air ±20kV, Contact ±18kV
- 4 Channels of ESD Protection
- Low Channel Input Capacitance of 0.65pF Typical
- Typically Used at High Speed Ports such as USB 2.0, IEEE1394, Serial ATA, DVI, HDMI, PCI
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

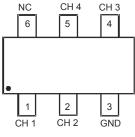
4 CHANNEL LOW CAPACITANCE TVS DIODE ARRAY

Mechanical Data

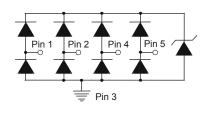
- Case: SOT363
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Matte Tin Finish annealed over Alloy 42 leadframe (Lead Free Plating). Solderable per MIL-STD-202, Method 208 (3)
- Weight: 0.006 grams (approximate)



Top View



Device Pinout



Device Schematic

Ordering Information (Note 4)

Part Number	Case	Packaging
DT2636-04S-7	SOT363	3000/Tape & Reel

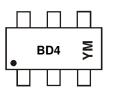
Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



BD4 = Product Type Marking Code YM = Date Code Marking Y = Year (ex: A = 2013) M = Month (ex: 9 = September)

Date Code Key

Year	201	3	2014		2015	20	16	2017		2018	2	2019
Code	A		В		С	[)	E		F		G
Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	1	5	6	7	8	0	0	N	П



Maximum Ratings (@T_A = +25°C, unless otherwise specified)

	1	1		
Characteristic	Symbol	Value	Unit	Conditions
Peak Pulse Current	IPP	6.5	А	8/20µs, From CH to GND
Peak Pulse Current	IPP	6.5	А	8/20µs, From GND to CH
Peak Pulse Power	P _{PP}	60	W	8/20µs, From CH to GND
ESD Protection – Contact Discharge	V _{ESD_Contact}	±18	kV	Standard IEC 61000-4-2
ESD Protection – Air Discharge	V _{ESD_Air}	±20	kV	Standard IEC 61000-4-2
Operating Temperature	T _{OP}	-55 to +85	°C	—
Storage Temperature	T _{STG}	-55 to +150	°C	—

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation Typical (Note 5)	PD	200	mW
Thermal Resistance, Junction to Ambient Typical (Note 5)	$R_{ hetaJA}$	625	°C/W

Electrical Characteristics (@T_A = +25°C, unless otherwise specified)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Conditions
Reverse Standoff Voltage	V _{RWM}	-	_	5.5	V	—
Channel Leakage Current (Note 6, 7)	I _R	-	1	10	nA	V _R = 2.5V
Reverse Breakdown Voltage	V _{BR}	7.0	_	9.5	V	I _R = 1mA, from CH to GND
Clamping Voltage, Positive Transients	V _{CL1}	-	6.8	_	V	I_{PP} = 1A, t_p = 8/20µs
Clamping Voltage, Positive Transients	V _{CL1}	-	9	_	V	$I_{PP} = 5A, t_p = 8/20 \mu s$
Clamping Voltage, Negative Transients	V _{CL2}	_	1.5	_	V	I _{PP} = 1A, t _p = 8/20µs
Forward Voltage	VF	_	0.7	_	V	I _F = 1mA, GND to CH
Dynamic Resistance	R _{DIFF}	_	0.4	_	Ω	I_{PP} = 1A, t_p = 8/20µs, CH to GND
Dynamic Resistance	R _{DIFF-R}	_	0.45	_	Ω	TLP, 20A, tp = 100 ns, CH to GND
Dynamic Resistance	R _{DIFF-F}	_	0.2	_	Ω	TLP, 20A, tp = 100 ns, GND to CH
CH to GND Capacitance		_	0.75	_	pF	$V_{(CH-GND)} = 0V, f = 1MHz$
	C _(CH-GND)		0.65	0.9	pF	V _(CH-GND) = 2.5V, f = 1MHz
Delta Ссн	Cchmax- Cchmin	_	0.04	_	pF	C _{CHMAX} -C _{CHMIN}

Notes: 5. Device mounted on FR-4 PCB pad layout (2oz copper) as shown on Diodes, Inc. suggested pad layout AP02001, which can be found on our website at http://www.diodes.com.

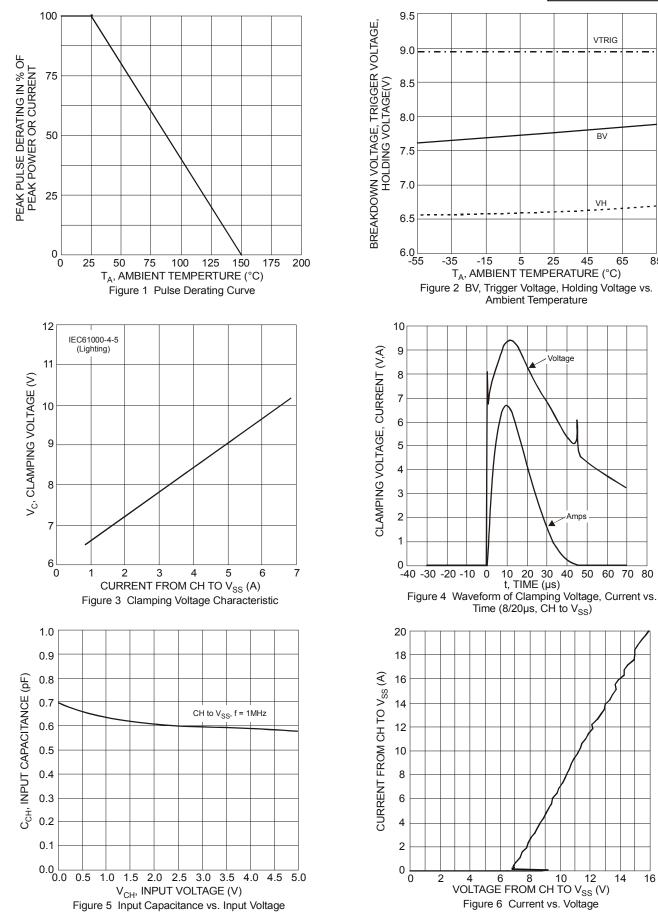
Short duration pulse test used to minimize self-heating effect.
Measured from pin 1, 2, 4 and 5 to GND.



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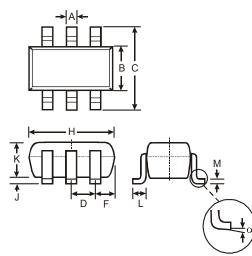
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Package Outline Dimensions

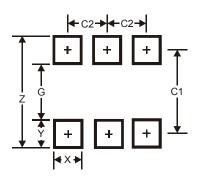
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT363							
Dim	Min	Max	Тур				
Α	0.10	0.30	0.25				
В	1.15	1.35	1.30				
С	2.00	2.20	2.10				
D		0.65 Typ					
F	0.40	0.45	0.425				
Н	1.80	2.20	2.15				
J	0	0.10	0.05				
κ	0.90	1.00	1.00				
L	0.25	0.40	0.30				
М	0.10	0.22	0.11				
α	0°	8°	-				
All	All Dimensions in mm						

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.5
G	1.3
Х	0.42
Y	0.6
C1	1.9
C2	0.65



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